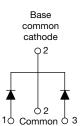


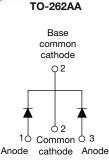
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 10 A



D²PAK (TO-263AB)





VS-20CTQ...S-M3

cathode Anode

Anode

VS-20CTQ ... -1-M3

PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 10 A							
V _R	35 V, 40 V, 45 V							
V _F at I _F	0.57 V							
I _{RM}	15 mA at 125 °C							
T _J max.	175 °C							
E _{AS}	13 mJ							
Package	D ² PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

FEATURES

- 175 °C T_J operation
- · Center tap configuration
- · Low forward voltage drop
- High frequency operation
- purity. • Hiah high temperature epoxv encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-20CTQ... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

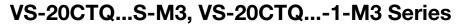
MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	А						
V _{RRM}	Range	35 to 45	V						
I _{FSM}	t _p = 5 μs sine	1060	А						
V _F	10 A _{pk} , T _J = 125 °C (per leg)	0.57	V						
TJ	Range	-55 to +175	°C						

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-20CTQ035S-M3 VS-20CTQ035-1-M3	VS-20CTQ040S-M3 VS-20CTQ040-1-M3	VS-20CTQ045S-M3 VS-20CTQ045-1-M3	UNITS
Maximum DC reverse voltage	V _R	35	40	45	V
Maximum working peak reverse voltage	V _{RWM}		40	45	v

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ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 145$ °C	20							
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	1060	A					
surge current per leg See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	265						
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 2.0 \ A, \ L = 6.5$	13	mJ						
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	2.0	А						

ELECTRICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS							
		10 A	T ₁ = 25 °C	0.64	v					
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.76						
See fig. 1	VFM ()	10 A	T ₁ = 125 °C	0.57						
		20 A	1j=125 C	0.68						
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C		2	mA					
See fig. 2		T _J = 125 °C	V _R = Rated V _R	15						
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 mm	8.0	nH						
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs						

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 175	°C				
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation See fig. 4	3.25					
Maximum thermal resistance, junction to case per package		nthJC	DC operation	1.63	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50					
Approximate weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque	maximum			12 (10)	(lbf · in)				
			Case style D ² PAK (TO-263AB)	20CTC 20CTC 20CTC	040S				
			Case style TO-262AA	20CTC 20CTC 20CTC	040-1				





VS-20CTQ...S-M3, VS-20CTQ...-1-M3 Series

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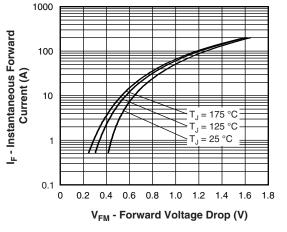


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

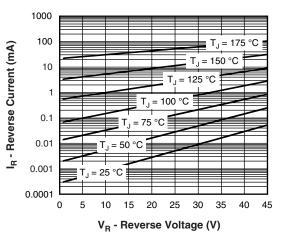


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

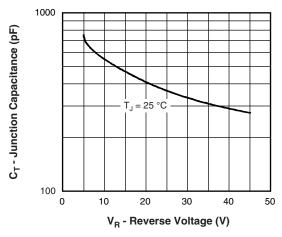
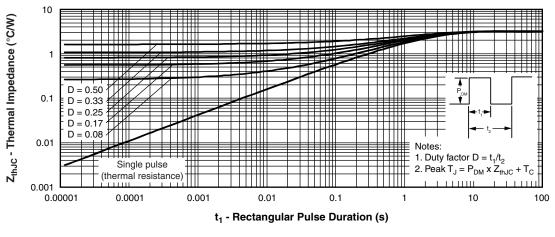


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



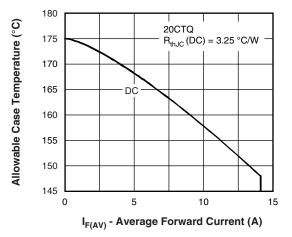


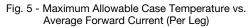
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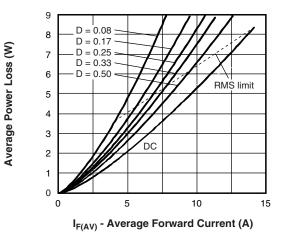


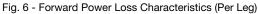
VS-20CTQ...S-M3, VS-20CTQ...-1-M3 Series

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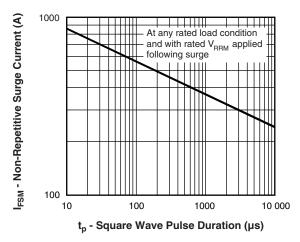


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

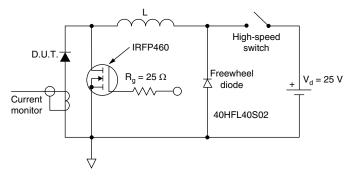


Fig. 8 - Unclamped Inductive Test Circuit

(1) Formula weeks

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

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VS-20CTQ...S-M3, VS-20CTQ...-1-M3 Series

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 $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \ x \ V_{FM} \ at \ (\mbox{I}_{F(AV)}/D) \ (see \ fig. \ 6); \\ \mbox{Pd}_{REV} = \ inverse \ power \ loss = \ V_{R1} \ x \ I_R \ (1 \ - \ D); \ I_R \ at \ V_{R1} = \ 80 \ \% \ rated \ V_R \ applied \end{array}$

ORDERING INFORMATION TABLE

Device code	VS-	20	С	т	Q	045	S	TRL	-M3
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
	<u> </u>	Visł	\bigcirc	nicondu	0	oduct	\bigcirc	\bigcirc	\bigcirc
	2 -		-	ng (20 A	•				
	3 -	Circ	cuit con	figuratio	n: C = c	commor	n catho	de	
	4 -	- T =	TO-220)					
	5 -	Sch	ottky "O	Q" series	s [035 = 3	5 V		
	6 -	Vol	tage rati	ings —		040 = 4			
	7 -	• S	= D ² PA	K (TO-2	63AB)	045 = 4	5 V		
	_	• -1	= TO-2	262AA					
	8 -	• N	one = tı	lbe					
		• TI	RL = tap	be and r	eel (left	orienteo	d - for D) ² PAK (1	FO-263/
	_	• TI	RR = tap	be and r	eel (righ	nt oriente	ed - for	D ² PAK	(TO-26
	9 -	-M3	3 = halo	gen-free	e, RoHS	S-compl	iant, an	d termiı	nation le

ORDERING INFORMATION		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-20CTQ035S-M3	50	Antistatic plastic tubes
VS-20CTQ035STRL-M3	800	13" diameter plastic tape and reel
VS-20CTQ035STRR-M3	800	13" diameter plastic tape and reel
VS-20CTQ040S-M3	50	Antistatic plastic tubes
VS-20CTQ040STRL-M3	50	13" diameter plastic tape and reel
VS-20CTQ040STRR-M3	800	13" diameter plastic tape and reel
VS-20CTQ045S-M3	800	Antistatic plastic tubes
VS-20CTQ045STRL-M3	50	13" diameter plastic tape and reel
VS-20CTQ045STRR-M3	50	13" diameter plastic tape and reel
VS-20CTQ150S-M3	800	Antistatic plastic tubes
VS-20CTQ150STRL-M3	800	13" diameter plastic tape and reel
VS-20CTQ150STRR-M3	50	13" diameter plastic tape and reel
VS-20CTQ045-1-M3	50	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS								
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164						
	TO-262AA	www.vishay.com/doc?96165						
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444						
	TO-262AA	www.vishay.com/doc?95443						
Packaging information		www.vishay.com/doc?96424						

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Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

Outline Dimensions



Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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Document Number: 95419

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